

IPC50N04S55R8ATMA1

IPC50N04S55R8ATMA1 Information



Part NumberIPC50N04S55R8ATMA1ManufacturerInfineon TechnologiesCategoryDiscrete Semiconductor Products
Transistors - FETs, MOSFETs - SingleDescriptionMOSFET N-CH 40V 50A 8TDFNPackage8-PowerTDFN
For the pricing/inventory/lead time, please contact
us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPC50N04S55R8ATMA1 Specifications

Manufacturer Part Number	IPC50N04S55R8ATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	50A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	7V, 10V
Vgs(th) (Max) @ Id	3.4V @ 13µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1090pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	42W (Tc)
Rds On (Max) @ Id, Vgs	5.8 mOhm @ 25A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TDSON-8
Package / Case	8-PowerTDFN
	Report errors?

IPC50N04S55R8ATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPC50N04S55R8ATMA1 Payment Methods



If you have any question about IPC50N04S55R8ATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com